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Single crystal growth and physical properties of YbPd₂Si₂

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Abstract.

We report the heat capacity and magnetic properties of single crystals of YbPd₂Si₂ grown from Sn flux. YbPd₂Si₂ is a non magnetic heavy fermion compound with electronic specific heat coefficient $\gamma = 95$ mJ/mol K² and Pauli paramagnetic susceptibility $\chi_0 = 0.0115$ emu/mol. The density of states of single crystal YbPd₂Si₂ is approximately half that of polycrystalline YbPd₂Si₂ while the strength of the Kondo effect in the single crystal is approximately twice that of poly crystal.

1. Introduction

In the study of quantum critical phenomena in highly correlated f electron systems, Yb compounds have been found to exhibit interesting quantum phenomena. β -YbAlB₄ exhibits heavy fermion superconductivity [1], YbT₂Zn₂₀ (T=transition metal) exhibits heavy fermion behavior where the electronic specific heat coefficient γ of YbCo₂Zn₂₀ reaches about 8 J/mol K² [2], and ferromagnetic quantum fluctuations have been observed in YbNi₄P₂ [3].

The tetragonal ThCr₂Si₂-type structure series is one of the most studied group of compounds. Among the Yb member compounds, YbRh₂Si₂ exhibits anomalous quantum critical behavior which cannot be explained by the conventional Hertz-Millis-Moriya (MHH) theory [4, 5, 6, 7]. In the paramagnetic heavy fermion compounds YbCu₂Si₂ and YbNi₂Ge₂ [8, 9], pressure induced magnetic order takes place. And superconductivity occurs in YbPd₂Ge₂ [10].

YbPd₂Si₂ is paramagnetic heavy fermion compound with ThCr₂Si₂-type structure whose γ is approximately 200 mJ/mol K² [11]. The lattice volume V is 165.074 Å³ [12]. On the other hand, YbNi₂Si₂ with the same electron count is an antiferromagnet with $T_N = 2.3$ K and V is 145.736 Å³ [13]. If YbNi₂Si₂ and YbPd₂Si₂ fit on the so-called Doniach phase diagram, then YbPd₂Si₂ will exhibit antiferromagnetic order under pressure. Actually, magnetic order has been observed above the critical pressure $p_c = 1$ GPa [14]. These pressure measurements have been performed on a polycrystalline sample with residual resistivity ratio (RRR) and residual resistivity of about 2 and 90 $\mu\Omega$ cm, respectively. High quality single crystals are necessary for the study of quantum critical phenomena. However, there is no report of the single crystal



growth for YbPd_2Si_2 . Therefore we have synthesized and performed magnetic property and specific heat measurements on YbPd_2Si_2 single crystal grown from Sn-flux.

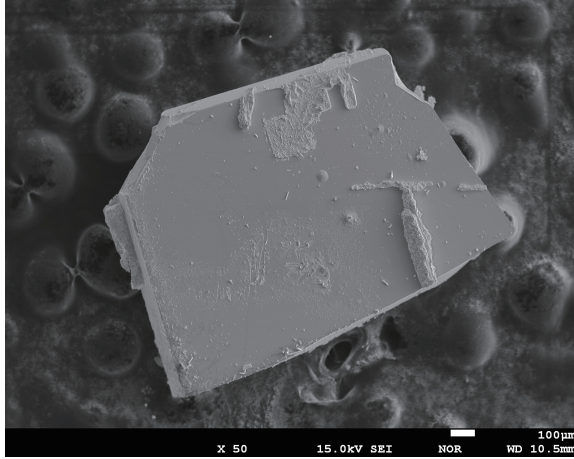


Figure 1. Scanning electron microscopic images of YbPd_2Si_2 .

2. Experimental

The single crystal of YbPd_2Si_2 were grown in Sn-flux method. 3N (99.9 %) Yb, 3N Pd, 6N Si and 6N Sn were reacted in the starting composition of 1:2:2:50. These materials were placed in an alumina crucible and sealed in an evacuated quartz tube. The sealed tubes were heated to 1150 °C, soaked for 12 hours, then cooled down to 500 °C in 96 hours. The excess Sn was spun off in a centrifuge. Figure 1 shows the scanning electron microscopic images of YbPd_2Si_2 .

The single phase of the tetragonal ThCr_2Si_2 structure was confirmed by the powder X-ray diffraction method. The crystal compositions and homogeneity were determined by using an electron micro-probe with wavelength dispersive spectrometers (electron probe micro analyzer(EPMA)-WDS; JEOL-8530F). We used the $\text{YbP}_5\text{O}_{14}$, Pd and Si as standard reference materials for EPMA. The chemical composition was determined to be Yb:Pd:Si = 1.00:1.83:2.08, indicating that the values are similar to the stoichiometric compositions of YbPd_2Si_2 , although the ratio of Pd is slightly small.

The magnetic susceptibility was measured using a commercial superconducting quantum interference device magnetometer (Quantum Design). The specific heat measurement was carried out by the relaxation method using a commercial physical property measurement system (PPMS; Quantum Design).

3. Results and discussion

Figure 2 shows the magnetic susceptibility as a function of temperature at 1 T with magnetic field applied parallel to the [001] direction. With decreasing temperature, the susceptibility increases to a broad maximum. In heavy fermion compounds such as CeRu_2Si_2 [15], such a broad maximum have been observed. Here the temperature of the maximum of susceptibility $T_{\chi_{max}}$ is 41 K. The $T_{\chi_{max}}$ of our single crystal is about two times that of the polycrystalline samples of the previous study. In the low temperature region, the susceptibility slightly increases with decreasing temperature, probably due to magnetic impurities. The maximum of susceptibility around $T_{\chi_{max}}$ is wider than that of poly crystal [16]. It would be caused by the impurity phases. If we neglect the magnetic impurity, we estimated $\chi(T=0) = 0.0115$ emu/mol, a large Pauli paramagnetic value.

Figure 3 shows the temperature dependence of the reciprocal magnetic susceptibility. Above 150 K, the temperature dependence of the inverse magnetic susceptibility can be fit by a

Curie-Weiss law with effective moment μ_{eff} and Weiss temperature θ_p of $4.54 \mu_B$ and -123 K, respectively, the effective moment being very close to the Hund's Rule value expected for Yb^{+3} $\mu_{\text{eff}} = 4.53 \mu_B$.

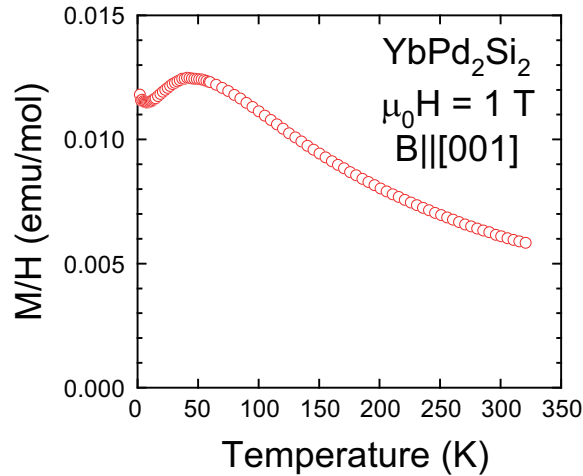


Figure 2. Temperature dependence of the magnetic susceptibility at 1 T for a magnetic field along [001] direction.

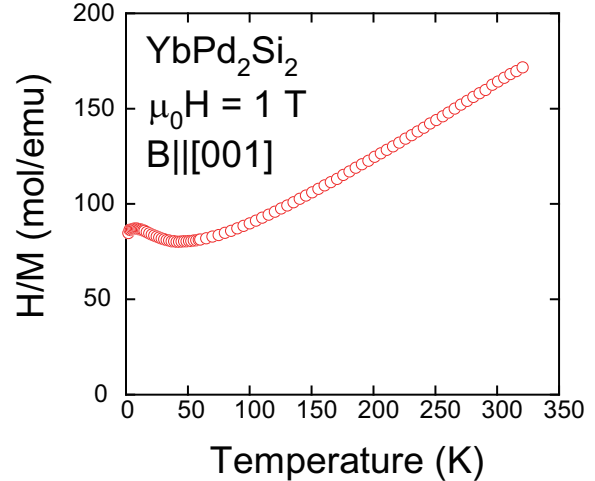


Figure 3. Temperature dependence of the reciprocal magnetic susceptibility at 1 T for a magnetic field along [001] direction.

Figure 4 shows the temperature dependence of the specific heat C . The inset in Fig. 4 shows C/T versus T^2 . Using the expression $C/T = \gamma + \beta T^2$, we estimate the value of the specific heat coefficient $\gamma = 95$ mJ/mol K² and $\beta = 0.555$ mJ/mol K⁴. This γ of our single crystal is approximately half that reported for the polycrystal.

The physical properties of single crystal YbPd_2Si_2 are similar to that of polycrystalline, indicating that single crystal YbPd_2Si_2 is a paramagnetic heavy fermion. However the γ , $T_{\chi_{\text{max}}}$ and χ_0 differ between them. We summarize the physical properties of single crystal and polycrystal YbPd_2Si_2 in table 1. χ_0 and γ are proportional to the density of states (DOS). χ_0 and γ of single crystal are about half those of polycrystal, indicating a DOS of single crystal about half that of polycrystal. In heavy fermion systems, $T_{\chi_{\text{max}}}$ is proportional to the Kondo temperature T_K [15], indicating that T_K of single crystal is about twice larger than that of polycrystal. Moreover, the electronic specific coefficient γ is roughly in inverse proportional to T_K [17]. γ is approximately half that of poly crystal. The difference of physical properties between the single crystal and polycrystal could be caused by the change of strength of Kondo effect. The strength of Kondo effect is changed by the electron or hole doping, the change of lattice volume etc. The defect at the Pd site can possibly change the number of electron and lattice volume. The difference of physical properties between single crystal and polycrystal could be caused by the defect at the Pd site.

4. Conclusion

We have synthesized single crystal YbPd_2Si_2 from Sn flux. The crystal structure was confirmed by powder X-ray diffraction and chemical composition was determined to be $\text{Yb}:\text{Pd}:\text{Si} = 1.00:1.83:2.08$. We have measured the specific heat and susceptibility of YbPd_2Si_2 . It was found that single crystal YbPd_2Si_2 is a non magnetic heavy fermion compound with the $\gamma = 95$ mJ/mol K² and $\chi_0 = 0.0115$ emu/mol.

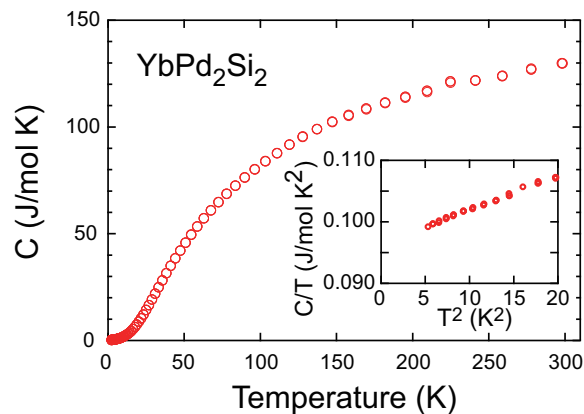


Figure 4. Temperature dependence of specific heat. The inset shows the C/T vs. T^2 .

Table 1. χ_0 , $T\chi_{max}$ and γ of poly crystal and single crystal .

sample	χ_0 (emu/mol)	$T\chi_{max}$ (K)	γ (mJ/mol K ²)
poly crystal (arc melt)	0.018 [16]	25 [16]	203 [11]
single crystal (Sn flux (this work))	0.0115	41	95

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